



Micro Commercial Components

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**TSMBJ1006C
 THRU
 TSMBJ1024C**

**Transient Voltage
 Protection Device
 75 to 320 Volts**

Features

- Oxide-Glass passivated Junction
- Bi-Directional protection in a single device
- Surge capabilities up to 100A@10/1000us or 400A@8/20us
- High Off-State impedance and Low On-State voltage
- Plastic material has UL flammability classification 94V-0

Mechanical Data

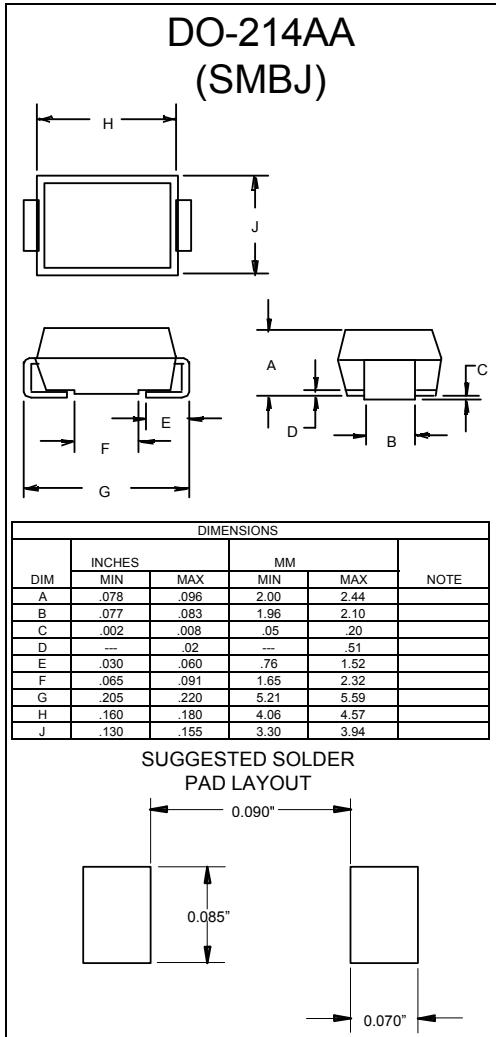
- Case : Molded plastic
- Polarity : None cathode band denotes
- Approx Weight : 0.093grams

Maximum Rating

Characteristic	Symbol	Value	Unit
Non-repetitive peak impulse current	I_{PP}	100A	10/1000us
Non-repetitive peak On-state current	I_{TSM}	50A	8.3ms, one-half cycle
Operating temperature range	T_{OP}	-40~150°C	
Junction and storage temperature range	T_J, T_{STG}	-55~150°C	

Thermal Resistance

Characteristic	Symbol	Value	Unit
Thermal Resistance junction to lead	$R_{\theta JL}$	20°C/W	
Thermal Resistance junction to ambient	$R_{\theta JA}$	100°C/W	On recommended pad layout
Typical positive temperature coefficient for breakdown voltage	$\Delta V_{BR}/\Delta T_J$	0.1%/°C	



TSMBJ1006C thru TSMBJ1024C



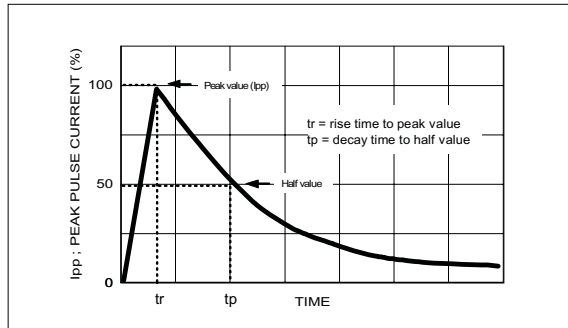
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ELECTRICAL CHARACTERISTIC @25°C Unless otherwise specified

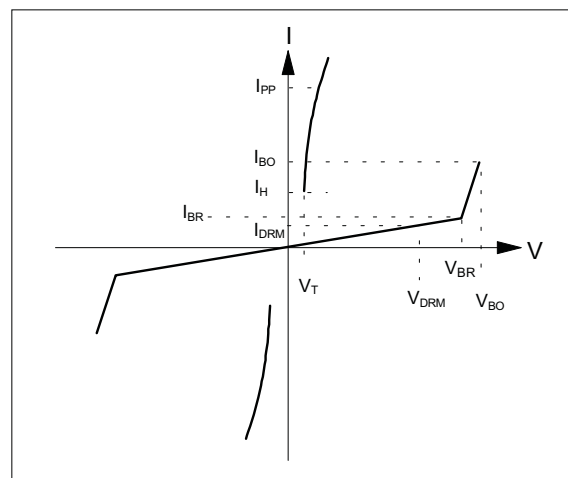
Parameter	Rated Repetitive Off-state Voltage	Off-state Leakage Current@V _{DRM}	Breakover Voltage	On-State Voltage @I _T =1.0A	Breakover Current	Holding Current	Off-State
Symbol	V _{DRM}	I _{DRM}	V _{BO}	V _T	I _{BO+}	I _H	C _J
Units	Volts	uA	Volts	Volts	mA	mA	pF
Limit	Max	Max	Max	Max	Max	Min	Typ.
TSMBJ1006C	75	5	98	5	800	150	200
TSMBJ1007C	90	5	130	5	800	150	120
TSMBJ1010C	140	5	180	5	800	150	120
TSMBJ1012C	160	5	220	5	800	150	120
TSMBJ1016C	190	5	265	5	800	150	80
TSMBJ1018C	220	5	300	5	800	150	80
TSMBJ1022C	275	5	350	5	800	150	80
TSMBJ1024C	320	5	400	5	800	150	80

MAXIMUM RATED SURGE WAVEFORM

Waveform	Standard	I _{pp} (A)
2/10 us	GR-1089-CORE	500
8/20 us	IEC 61000-4-5	400
10/160 us	FCC Part 68	200
10/700 us	ITU-T K20/21	200
10/560 us	FCC Part 68	150
10/1000 us	GR-1089-CORE	100



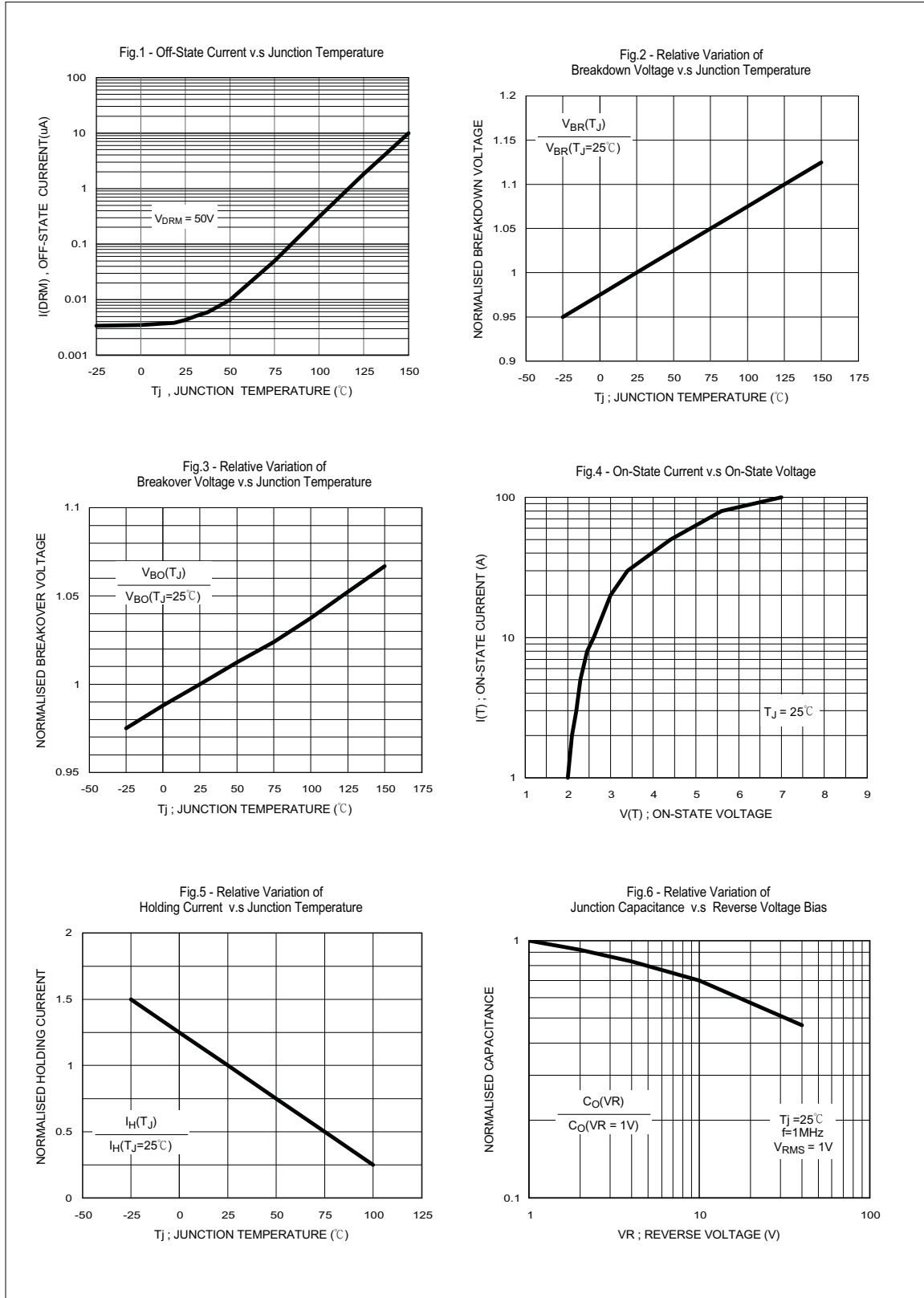
Symbol	Parameter	
V _{DRM}	Stand-off voltage	
I _{DRM}	Leakage current at stand-off voltage	
V _{BR}	Breakdown voltage	
I _{BR}	Breakdown current	
V _{BO}	Breakover voltage	
I _{BO}	Breakover current	
I _H	Holding current	NOTE: 1
V _T	On state voltage	
I _{PP}	Peak pulse current	
C _O	Off-state capacitance	NOTE: 2



NOTE :

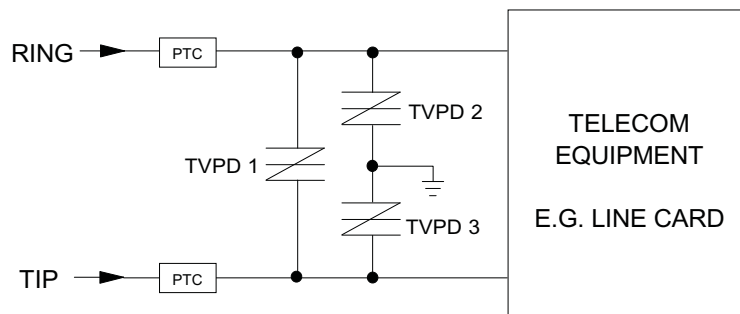
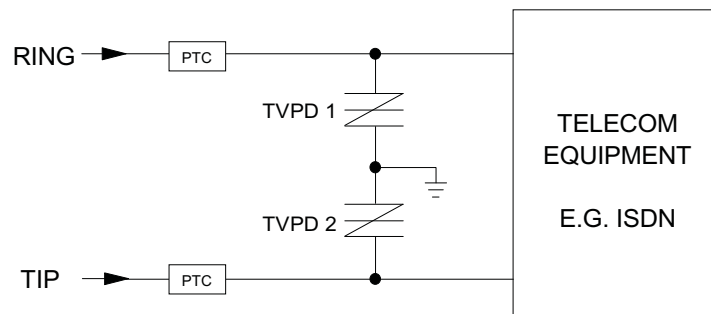
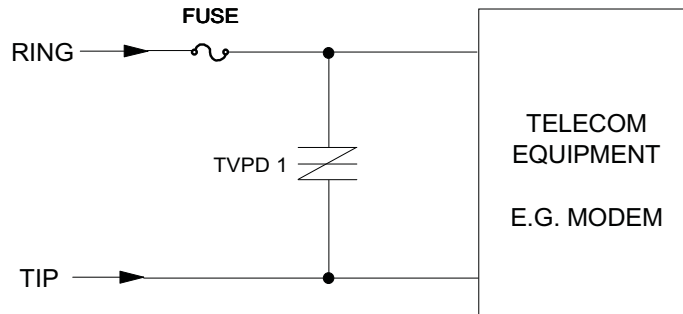
1. $I_H > (V_L / R_L)$ If this criterion is not obeyed, the TSPD triggers but does not return correctly to high-resistance state. The surge recovery time. It does not exceed 30ms.
2. Off-state capacitance measured at $f=1.0\text{MHz}$, 1.0Vrms signal, $V_R=2\text{Vdc}$ bias.

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TYPICAL APPLICATION CIRCUITS



The PTC (Positive Temperature Coefficient) is an overcurrent protection device.

MARKING CODE

